MIES		Docket Name to (Outland)			
10. · · · · · · · · · · · · · · · · · · ·	\	Docket Number (Optional) FIS920020166US1	Application Number 10/604,487		
	RMATION DISCLOSURE CITATION	Applicant(s)			
AUG 1 4 2003	U' (Use several sheets if necessary)	Hendrik F. Hamann et al.			
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ot considered. Incid	ide copy of this form with next communication to applicant,				

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		Docket Number (Optional)	Application Number		
16/4 ×		FIS920020166US1	10/604,487		
INFORMATION DISCLOSURE CITATION		Applicant(s)			
	(Use several sheets if necessary)	Hendrik F. Hamann et al.			
AUG 1 4 LOV	<u>. </u>	Filing Date 07/25/2003	Group Art Unit		
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		Docket Number (Optional)	A - U - A - N		
OTPE		FIS920020166US1	Application Number 10/604,487		
INFORMATION DISCLOSURE CITATION		Applicant(i) Hendrik F. Hamann et al.			
AUG 1 4 2003 (Use several sheets if necessary)		Filing Date	Group Art Unit		
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ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18

Stylesheet Version v18.0

Title of Invention

SYSTEM AND METHODS OF ALTERING A VERY SMALL SURFACE AREA

Application Number:

10/604,487

Confirmation Number:

First Named Applicant:

Hendrik Hamann

Attorney Docket Number:

FIS920020166US1

Art Unit:

1763

Examiner:

MAUREEN G. ARANCIBIA

Search string:

(4550257 or 4925139 or 5865978 or 6002471 or 4880496 or 6078055).pn

US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
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Signature

Examiner Name	Date	
Maineen Panchin	09/13/2004	